Journal of Materials Chemistry A



View Article Online

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Cite this: J. Mater. Chem. A, 2018, 6, 8210

Received 11th March 2018 Accepted 7th April 2018

DOI: 10.1039/c8ta02284d

rsc.li/materials-a

Three-dimensional hollow spheres of the tetragonal-spinel MgMn₂O₄ cathode for high-performance magnesium ion batteries[†]

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We report a simple and template-free method for preparing uniform tetragonal-spinel $MgMn_2O_4$ (T- $MgMn_2O_4$) hollow spheres, which selfassembled from small sized nanocrystals. The obtained T- $MgMn_2O_4$ hollow spheres with a micro/nanostructure exhibit excellent rate performance and long cycle life as the cathode for magnesium ion batteries.

Rechargeable magnesium ion batteries (MIBs) have recently drawn a great deal of attention as an attractive alternative to lithium ion batteries (LIBs), due to their potential suitability for large energy storage systems.¹ When compared with LIBs, MIBs show a high energy density, raw material abundance, and high level of safety in electrolytes.^{2,3} However, the strong polarity and sluggish solid state diffusion of divalent Mg²⁺ cations have made it difficult to develop a promising Mg-based cathode material.⁴ So far, only a few materials have been proposed as suitable Mg²⁺ hosts, mainly based on electroneutrality and screening effects.⁵⁻⁷ Chevrel phase materials, such as Mo₆T₈ (T = S or Se) and MoS₂, are typical cluster-containing compounds with electroneutrality between Mg²⁺ ions and anionic frameworks. Previous studies have proposed that such materials can provide a high-speed channel for the effective migration of Mg²⁺ ions in the host, resulting in stable charge-discharge cycling and high-rate charge-discharge capability.8,9 Nevertheless, the low capacity and operating voltage of such materials have

limited their further application. The screening effect, which shields the charge of divalent Mg²⁺ cations with oxygen or other anions, is another effective method for designing novel cathode materials for MIBs. Recent studies suggest that Mg²⁺ cations can be inserted/extracted from layered hosts, such as V2O5 and birnessite MnO₂, when the Mg²⁺ ions are hydrated.¹⁰⁻¹³ However, it is worth noting that the kinetics of these materials would always be influenced by incomplete charge screening. To achieve a high operating voltage and good kinetics, the characteristic three-dimensional (3D) pathway of spinel materials could be favorable. Specifically, manganese oxide, one of the most important 3D cathode materials for LIBs, has also been applied as a cathode material for MIBs recently.14 For instance, λ -MnO₂ has been employed as an effective 3D host for Mg²⁺ migration.^{15,16} Persson undertook systematic calculations regarding the use of spinel compounds as MIB cathodes.17 Furthermore, the intercalation reaction of Mg²⁺ into spinel-type Mn₂O₄ was recently observed directly.¹⁸⁻²⁰ Despite these successful steps, application of such new concepts is limited by their complex synthesis methods and phase transformations during electrochemical processes. It is therefore a great challenge to synthesize a promising 3D electrode material for MIBs using a general method.

Taking the strong electrostatic interaction and poor dynamics of divalent Mg²⁺ into consideration, designing a unique nanocrystalline structure is critical for improving its electrochemical performance. This is because the nano-structure offers a short transport length for ions/electrons and also a large electrode/ electrolyte interface area.^{21–24} In particular, hollow micro/ nanostructures have received much attention owing to their excellent properties and great potential as electrochemical devices.^{25–29} For example, uniform Fe₃O₄ and NiCo₂O₄ hollow spheres showed excellent lithium storage ability and are a potential anode material for LIBs and supercapacitors.^{30–33} Hence, it is desirable, yet very challenging, to design and synthesize hollow micro/nanostructured cathode materials for MIB.

Herein, we design and fabricate unique tetragonal-spinel MgMn₂O₄ (T-MgMn₂O₄) hollow spheres *via* solvothermal

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assisted solid phase reaction technology for use as the cathode material for MIBs for the first time. The uniform hollow spheres self-assembled from nanoparticles with a diameter of ten nanometers and form a 3D hierarchical architecture. Electrochemical characterization demonstrated that magnesium ions could be reversibly intercalated into the T-MgMn₂O₄ host with a high operation plateau of 3.2 V *versus* Mg²⁺/Mg. A high reversible capacity of 261.5 mA h g⁻¹ was delivered at a current of 100 mA g⁻¹ with superior long-term cycling stability.

Uniform T-MgMn₂O₄ hollow spheres successfully prepared via a thermal annealing process. The formation of uniform MgMn-glycerate precursor spheres was a key step in achieving the hollow structures. To elucidate the formation of the unique hollow crystalline structures as a function of annealing temperature, scanning electron microscopy (SEM), transition electron microscopy (TEM), and X-ray diffraction (XRD) analyzes were carried out, as shown in Fig. 1, S1 and S2.† The SEM image in Fig. 1a shows as-prepared MgMn-glycerate precursor spheres that were highly dispersed with a diameter of 1 µm. With increasing annealing temperature, particularly above 400 °C, the smooth surface of the precursor spheres gradually became a rough surface from the formation of nanoparticles (Fig. 1e-h), even though the spherical morphology showed no obvious change (Fig. 1b-d). Some broken hollow spheres were found in the treated samples with the increase of temperature, as displayed in Fig. 1g and h. The TEM images in Fig. 1i-l illustrate that the decomposition of MgMn-glycerate precursors results in a morphological transformation from solid spheres to the final hollow spheres. It is worth noting that the morphological evolution was accompanied by different XRD spectra (Fig. S1⁺). Between 400 and 600 °C, the decomposition of MgMn-glycerate precursors resulted in the intensity of typical diffraction features for T-MgMn₂O₄ appearing and increasing with temperature, indicating the structural evolution from an amorphous to a highly crystalline structure. The structural evolution was more obvious from the thermogravimetry (TG) data (Fig. S2[†]) where it was seen that the decomposition of MgMn-glycerate mainly took



Fig. 1 SEM and TEM images of T-MgMn₂O₄ hollow spheres at different growth stages: (a, e, i) precursor, (b, f, j) at 400 °C, (c, g, k) at 500 °C, and (d, h, l) at 600 °C.



Fig. 2 (a) Rietveld refinement of the XRD pattern for T-MgMn₂O₄. The inset is the model of $MgMn_2O_4$. (b) Atomic model of $LiMn_2O_4$ spinel. (c) Atomic model of T-MgMn₂O₄. (d) Calculated 3D transfer channels in T-MgMn₂O₄.

place between 250 and 300 °C. Furthermore, to confirm accurate sample compositions at different temperatures, the elemental ratios and distribution of Mg, Mn, and O atoms were characterized (Fig. S3†). The elements were found to be distributed uniformly and the atomic ratio of Mg/Mn/O gradually tended to the stoichiometric ratio of T-MgMn₂O₄ with increasing temperature.

The crystalline structure and morphology of hollow spheres annealed at 600 °C (T-MgMn₂O₄-600) will be described further. A typical XRD pattern of T-MgMn₂O₄-600 is illustrated in Fig. 2a. All diffraction features were fully indexed to the tetragonal crystal structure (space group I4,/AMDS). GASA Rietveld refinement of this XRD pattern gave the lattice constants of a =5.729246 Å, b = 5.729246 Å, c = 9.326452 Å, and a volume of $V = 306.134 \text{ Å}^3$, with a high quality fit ($R_p = 4.09\%$ and $R_{wp} =$ 5.89%), even though there was a small secondary phase. The atomic model of T-MgMn₂O₄ is very similar to that of cubicspinel LiMn₂O₄, as shown in Fig. 2b and c. It can be seen that Mg atoms in the crystalline structures are located on the tetragonal sites and were surrounded by six atoms to form an octahedron. This result indicates that both structures have similar 3D channels for cation migration. The only difference is that $T-MgMn_2O_4$ is the stable phase via the Jahn-Teller transformation of the cubic spinel structure and leads to a unique occupation of different atoms with different space groups, e.g., Mg, Mn, and O atoms occupy the 4a, 8d, and 16h sites for T-MgMn₂O₄, respectively. The possible ion transfer channels were further confirmed by first principles density functional theory (DFT) calculations based on the energy barrier. As shown in Fig. 2d, the Mg^{2+} ions are transferred between 4a sites through the Mn-O plane via a 3D channel. Most importantly, the low energy barrier (270 meV) suggests promising electrochemical performance for Mg ion batteries (Fig. S4[†]). In addition, the DFT calculations also gave the operation voltage U:

 $U = \frac{\Delta G}{nFe} = \frac{E(\text{Mn}_2\text{O}_4) + E(\text{Mg}^{2+}) - E(\text{Mg}\text{Mn}_2\text{O}_4)}{nFe}, \text{ where } \Delta G$ stands for Gibbs free energy, *F* is the Faraday's constant, and *n* is the number of electrons, suggesting a possible charge plateau at 3.2 V in MIBs. This means that T-MgMn_2O_4-600 is a promising cathode material for MIBs.

A typical T-MgMn₂O₄-600 hollow sphere sample was characterized by SEM and TEM. Low magnification SEM (Fig. 3a) shows that these hollow spheres were highly uniform, with a diameter of about 1 μ m, and self-assembled from 10 nm nanoparticles. The inset image in Fig. 3a shows a broken sphere that illustrates that the sphere is hollow. TEM characterization revealed the well-defined hollow structure with a shell thickness of several tens of nanometers, as displayed in Fig. 3b. The crystal lattice spacing of 0.488 nm shown in Fig. 3c corresponds to the planes of (211), (200), and (112) for T-MgMn₂O₄-600, which agree well with the XRD results. Additionally, energydispersive X-ray spectrometry (EDS) of T-MgMn₂O₄-600 confirmed that the elemental composition (Fig. 3d) of the target tetragonal spinel was composed of Mg, Mn, and O with a mole ratio of 1/2/4, respectively, and that all of the elements were evenly distributed. N2 sorption/desorption measurements of T-MgMn₂O₄-600 showed a Brunauer-Emmett-Teller (BET) surface area of 31.96 $m^2 g^{-1}$ (Fig. S5[†]) and provided more contact between the electrode and electrolyte.

The electrochemical properties of T-MgMn₂O₄-600 were evaluated using a three-electrode system with an aqueous electrolyte solution (1 M MgSO₄). Fig. 4a shows the charge– discharge profiles of T-MgMn₂O₄ at different cycles, presenting a high operating voltage around 0.7 V vs. Ag/AgCl, which is



Fig. 3 Morphological characterization of $T-MgMn_2O_4$ -600: (a) SEM, (b) TEM, and (c) HRTEM. (d) Elemental maps showing a uniform distribution of Mg (green), Mn (red), and O (dark blue).



Fig. 4 (a) Charge–discharge profile at different cycle numbers for T- $MgMn_2O_4$ -600. (b) Specific capacity at different current rates. (c) Cycling performance at a current of 100 mA g⁻¹.

corresponding to 3.2 V vs. Mg/Mg^{2+} , which is consistent with the theoretical calculation results. The cyclic voltammetry (CV) curves for the first four cycles are displayed in Fig. S6,† and are consistent with the redox couples on the charge-discharge profiles in Fig. 4a. A high discharge capacity of 261.5 mA h g^{-1} was obtained at a current of 100 mA g^{-1} for this outstanding cathode material. This high capacity is thought to arise from the unique 3D channels, as evidenced by the first principles calculations. The performance at various current rates is depicted in Fig. 4b, showing specific capacities of 183.5 and 152.8 mA h g^{-1} at the current densities of 150 and 200 mA g^{-1} , respectively. Even at a very high rate of 300 mA g^{-1} , the T-MgMn₂O₄ hollow spheres retained a specific capacity of 92.6 mA h g^{-1} . To the best of our knowledge, ours is the only presentation of a successful high-voltage cathode with a high discharge capacity for MIB applications, which is attributed to its unique crystal structure. Even though Mg²⁺ ions typically present a strong polarity with inferior electrochemical performance, the hollow T-MgMn₂O₄-600 material showed a high reversible capacity retention with a nearly 100% coulombic efficiency after 360 cycles at a current of 100 mA g^{-1} (Fig. 4c) and the electrochemical performance achieved in this work is superior to other previous literature results (Table S1[†]), indicating good cycling stability. These results confirmed that Mg²⁺ ions can be reversibly inserted into the T-MgMn₂O₄ host.

In order to elucidate the relationship between the structure and electrochemical performance, X-ray absorption spectroscopy (XAS) combined with HRTEM at various points during the charge/discharge process was investigated. With the deintercalation/intercalation of Mg^{2+} ions from the crystalline structure, the X-ray absorption near-edge structure (XANES) spectra at the Mn K-edge (Fig. S7a and b†) show a continuous shift in the high/low energy direction, respectively. On the other hand, extended X-ray absorption fine structure (EXAFS) spectra at the Mn K-edge (Fig. S7c†) also provide direct evidence that no significant changes concerning the local geometry of Mn atoms occur. In order to further confirm the working mechanism of the T-MgMn₂O₄-600. In order to further confirm the working mechanism of the T-MgMn₂O₄-600, the Mn 2p XPS spectroscopy at different charge/discharge stations were collected in the Fig. S8[†] to further prove this electronic change. From the significant shifting of $2p_{1/2}$ and $2p_{3/2}$ peaks, it is reasonable to believe that the extraction/insertion of Mg²⁺ ions in the spinel T- $MgMn_2O_4$ actually had a pronounced effect on the $Mn^{3+/4+}$ redox couple. Moreover, the elemental ratio characterization for samples at different charge/discharge states was also carried out by ICP-AES, as displayed in Fig. S9.† It can be observed that the Mn/Mg ratio increases with the Mg²⁺ extraction from 1.76 to 4.94, then decreasing to 1.83 after discharging to -0.6 V. The relatively low Mn/Mg ratio, compared with that of the perfect MgMn₂O₄ and Mn₂O₄ model, can be assigned to the small remaining amount of the Mg6MnO8 phase. Based on these experimental proofs and simulations, we propose that the electrochemical mechanism of T-MgMn₂O₄ is similar to that of the commercial LiMn₂O₄ system. This means that the Mg²⁺ migration does not influence the crystal structure. A lack of structural changes during the electrochemical process does not mean there is no electronic evolution. To further study the structural change, ex-HRTEM characterization of samples at different cycles was carried out, as displayed in Fig. S10,† where it can be seen that the crystal lattice always corresponded to the T-MgMn₂O₄ structure irrespective of the number of cycles.

In summary, we have developed a novel two-step general method to synthesize uniform T-MgMn₂O₄ hollow spheres with a micro/nanostructure. The uniform T-MgMn₂O₄ hollow spheres with a wall thickness of tens of nanometers self-assembled from many smaller nanocrystals. Electrochemical characterization showed that these T-MgMn₂O₄ hollow spheres exhibit superior electrochemical performance for MIBs, with a high reversible discharge capacity of 261.5 mA h g⁻¹ and a high operation voltage of 3.2 V *versus* Mg²⁺/Mg, and provide excellent cycling performance and rate capability. This work not only demonstrates the successful application of T-spinel materials as cathodes for MIBs, but also presents a new general method for developing other novel electrodes for energy storage.

Conflicts of interest

There are no conflicts to declare.

Acknowledgements

This work was supported by the National Natural Science Foundation of China (NSFC 11605002, 11705015) and China Postdoctoral Science Foundation (2015M580925). The help in measuring the XAS spectra from Beijing Synchrotron Radiation Facility (BSRF) is highly appreciated.

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